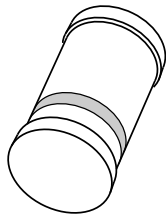


# DATA SHEET



## **BA682; BA683** Band-switching diodes

Product specification  
Supersedes data of April 1992  
File under Discrete Semiconductors, SC01

1996 Mar 13

## Band-switching diodes

## BA682; BA683

### FEATURES

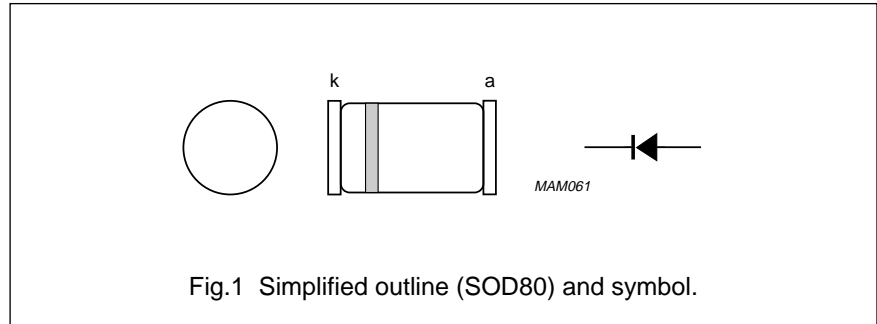
- Continuous reverse voltage:  
max. 35 V
- Continuous forward current:  
max. 100 mA
- Low diode capacitance:  
max. 1.5 pF
- Low diode forward resistance:  
max. 0.7 to 1.2  $\Omega$ .

### APPLICATION

- Band-switching in VHF television tuners.

### DESCRIPTION

Planar high performance band-switching diodes in a glass SOD80 SMD package.



### LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	MIN.	MAX.	UNIT
$V_R$	continuous reverse voltage	–	35	V
$I_F$	continuous forward current	–	100	mA
$T_{stg}$	storage temperature	–65	+150	$^{\circ}\text{C}$
$T_j$	junction temperature	–	150	$^{\circ}\text{C}$

### ELECTRICAL CHARACTERISTICS

$T_j = 25\text{ }^{\circ}\text{C}$  unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MAX.	UNIT
$V_F$	forward voltage	$I_F = 100\text{ mA}$ ; see Fig.2	1.0	V
$I_R$	reverse current	see Fig.3 $V_R = 20\text{ V}$ $V_R = 20\text{ V}$ ; $T_j = 75\text{ }^{\circ}\text{C}$	50 1	nA $\mu\text{A}$
$C_d$	diode capacitance	$f = 1\text{ MHz}$ ; $V_R = 1\text{ V}$ ; see Fig.4	1.5	pF
$C_d$	diode capacitance BA682 BA683	$f = 1\text{ MHz}$ ; $V_R = 3\text{ V}$ ; see Fig.4	1.25 1.20	pF pF
$r_D$	diode forward resistance BA682 BA683	$I_F = 3\text{ mA}$ ; $f = 200\text{ MHz}$ ; see Fig.5	0.7 1.2	$\Omega$ $\Omega$
$r_D$	diode forward resistance BA682 BA683	$I_F = 10\text{ mA}$ ; $f = 200\text{ MHz}$ ; see Fig.5	0.5 0.9	$\Omega$ $\Omega$

# Band-switching diodes

# BA682; BA683

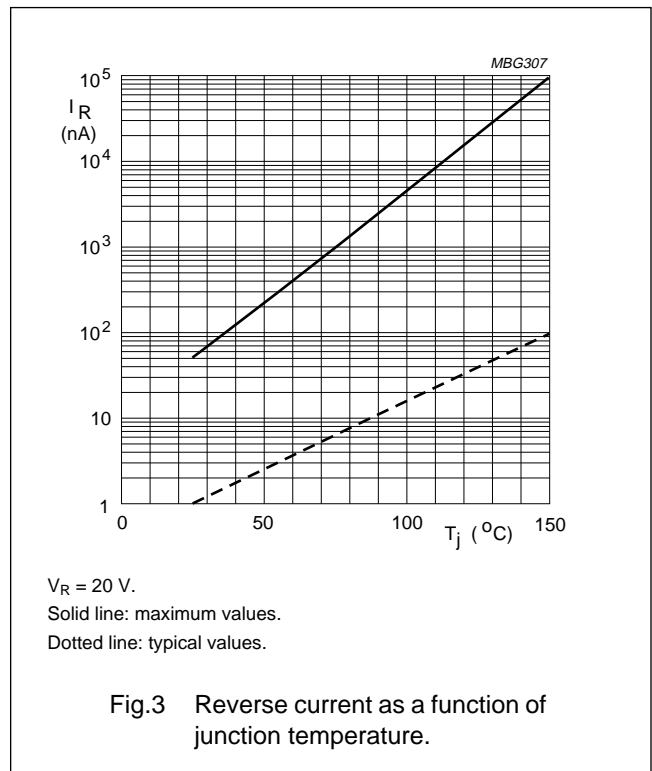
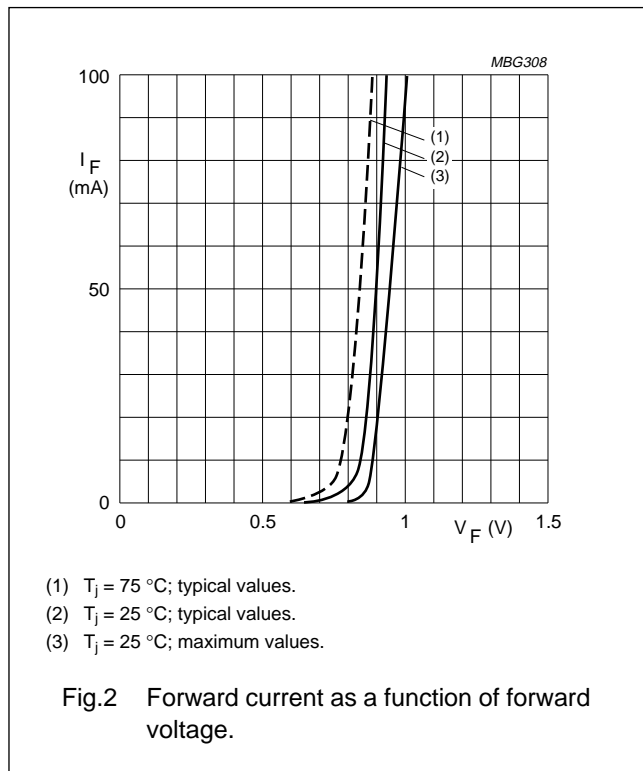
## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$R_{th\ j-tp}$	thermal resistance from junction to tie-point		300	K/W
$R_{th\ j-a}$	thermal resistance from junction to ambient	note 1	600	K/W

**Note**

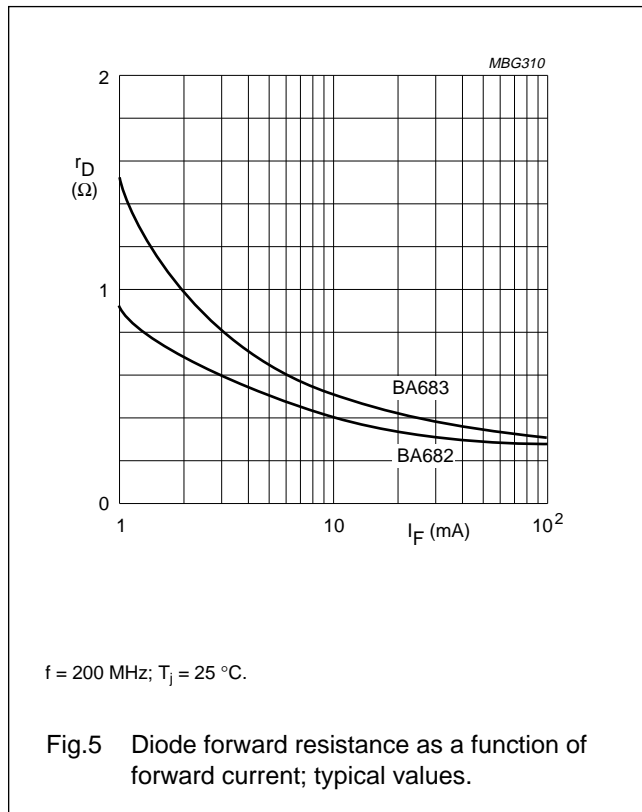
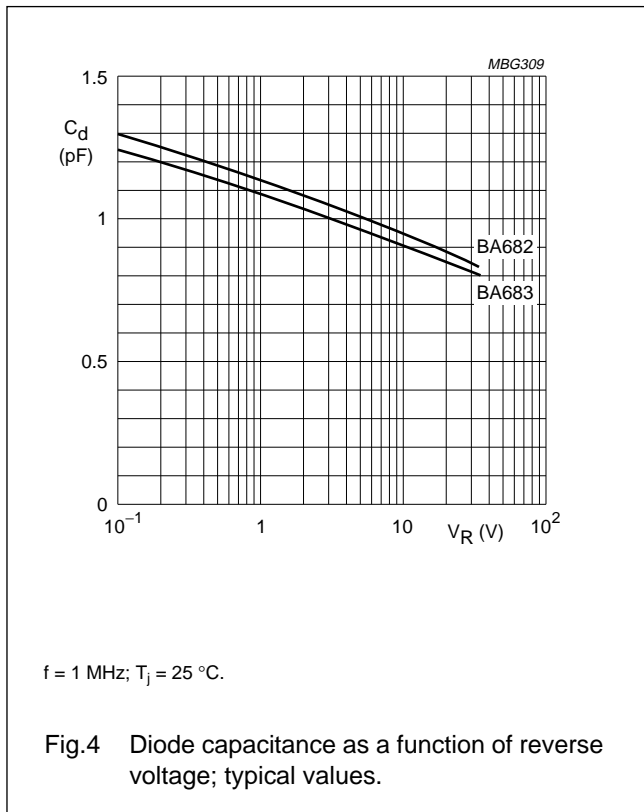
1. Device mounted on a FR4 printed-circuit board.

## GRAPHICAL DATA



Band-switching diodes

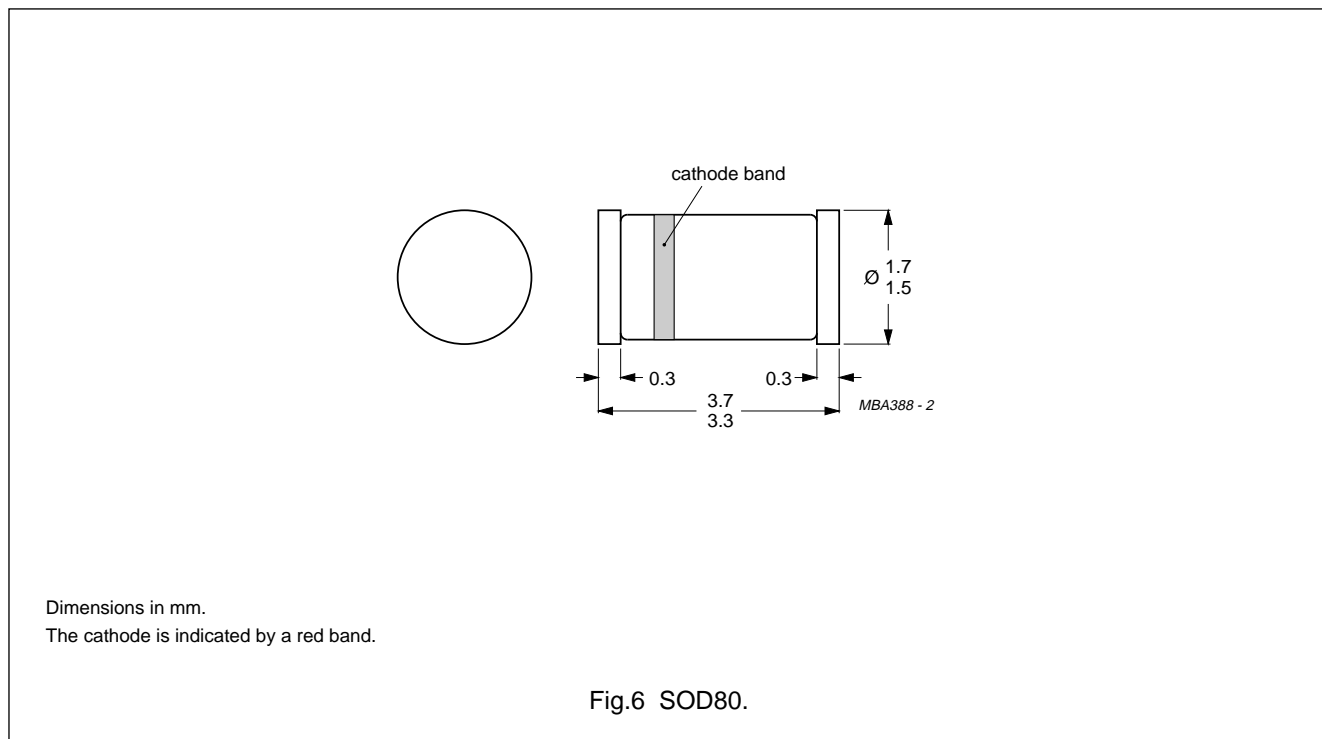
BA682; BA683



Band-switching diodes

BA682; BA683

PACKAGE OUTLINE



DEFINITIONS

<b>Data Sheet Status</b>	
Objective specification	This data sheet contains target or goal specifications for product development.
Preliminary specification	This data sheet contains preliminary data; supplementary data may be published later.
Product specification	This data sheet contains final product specifications.
<b>Limiting values</b>	
Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.	
<b>Application information</b>	
Where application information is given, it is advisory and does not form part of the specification.	

LIFE SUPPORT APPLICATIONS

These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips for any damages resulting from such improper use or sale.